



Order



Support & 2.0 Community



CSD75208W1015

SLPS512A - JULY 2014 - REVISED MAY 2017

CSD75208W1015 Dual 20-V Common Source P-Channel NexFET™ Power MOSFET

1 Features

- **Dual P-Channel MOSFETs**
- **Common Source Configuration**
- Small Footprint 1 mm x 1.5 mm
- Gate-Source Voltage Clamp
- Gate ESD Protection -3 kV
- Pb Free
- **RoHS** Compliant
- Halogen Free

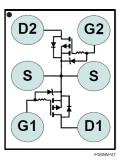
Applications 2

- **Battery Management**
- Load Switch
- **Battery Protection**

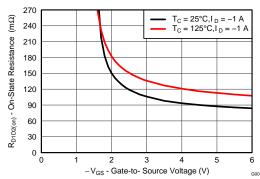
3 Description

This device is designed to deliver the lowest onresistance and gate charge in the smallest outline possible with excellent thermal characteristics in an ultra-low profile. Low on-resistance coupled with the small footprint and low profile make the device ideal for battery operated space constrained applications.





R_{D1D2(on)} vs V_{GS}



Product Summary								
T _A = 25°C	;	TYPICAL VAL	UE.	UNIT				
V _{DS}	Drain-to-Source Voltage	-20		V				
Qg	Gate Charge Total (-4.5 V)	1.9		nC				
Q_{gd}	Gate Charge Gate-to-Drain	0.23		nC				
R _{DS(on)}		$V_{GS} = -1.8 V$	100	mΩ				
	Drain-to-Source On-Resistance	$V_{GS} = -2.5 V$	70	mΩ				
		$V_{GS} = -4.5 V$		mΩ				
		$V_{GS} = -1.8 V$	190	mΩ				
R _{D1D2(on)}	Drain-to-Drain On-Resistance	$V_{GS} = -2.5 V$	120	mΩ				
		$V_{GS} = -4.5 V$	90	mΩ				
V _{GS(th)}	Threshold Voltage	-0.8		V				

Ordering Information⁽¹⁾

Device	Qty	Media	Package	Ship						
CSD75208W1015	3000	7-Inch Reel								
CSD75208W1015T	250	7-Inch Reel	Wafer Level Package	Tape and Reel						

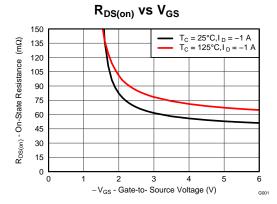
(1) For all available packages, see the orderable addendum at the end of the data sheet.

Absolute Maximum Ratings

T _A = 2	5°C	VALUE	UNIT
V_{DS}	Drain-to-Source Voltage	-20	V
V_{GS}	Gate-to-Source Voltage	-6	V
	Continuous Drain-to-Drain Current, $T_C = 25^{\circ}C$	-1.6	А
I _{D1D2}	Pulsed Drain-to-Drain Current, $T_{C} = 25^{\circ}C^{(1)}$	-22	А
	Continuous Source Pin Current	-3	А
I _S	Pulsed Source Pin Current ^{(1) (2)}	-39	А
	Continuous Gate Clamp Current	-0.5	А
I _G	Pulsed Gate Clamp Current ⁽¹⁾	-7	А
PD	Power Dissipation	0.75	W
T _J , T _{stg}	Operating Junction and Storage Temperature Range	-55 to 150	°C

(1) Max $R_{\theta JA}$ = 165°C/W, pulse duration ≤100 µs, duty cycle ≤1%

(2) Both devices in parallel



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Revision History 4

C	Changes from Original (July 2014) to Revision A				
•	Changed Figure 1.	4			
•	Added Community Resources and Receiving Notification of Documentation Updates sections to Device and				
	Documentation Support.	7			

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5 Specifications

5.1 Electrical Characteristics

 $T_A = 25^{\circ}C$ unless otherwise stated

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
STATIC C	CHARACTERISTICS		·			
BV_{DSS}	Drain-to-Source Voltage	$V_{GS} = 0 \text{ V}, \text{ I}_{DS} = -250 \mu\text{A}$	-20			V
BV_{GSS}	Gate-to-Source Voltage	$V_{DS}=0~V,~I_G=-250~\mu A$	-6.1		-7.2	V
I _{DSS}	Drain-to-Source Leakage Current	$V_{GS} = 0 V, V_{DS} = -16 V$			-1	μA
I _{GSS}	Gate-to-Source Leakage Current	$V_{DS} = 0 V, V_{GS} = -6 V$			-100	nA
V _{GS(th)}	Gate-to-Source Threshold Voltage	$V_{DS} = V_{GS}, \ I_{DS} = -250 \ \mu A$	-0.5	-0.8	-1.1	V
		$V_{GS} = -1.8 \text{ V}, I_D = -1 \text{ A}$		100	150	mΩ
R _{DS(on)}	Drain-to-Source On-Resistance	$V_{GS} = -2.5 \text{ V}, \text{ I}_{D} = -1 \text{ A}$		70	88	mΩ
		$V_{GS} = -4.5 \text{ V}, I_D = -1 \text{ A}$		56	68	mΩ
		$V_{GS} = -1.8 \text{ V}, I_{D1D2} = -1 \text{ A}$		190	285	mΩ
R _{D1D2(on)}	Drain-to-Drain On-Resistance	$V_{GS} = -2.5 \text{ V}, \text{ I}_{D1D2} = -1 \text{ A}$		120	150	mΩ
		$V_{GS} = -4.5 \text{ V}, \text{ I}_{D1D2} = -1 \text{ A}$		90	108	mΩ
9 _{fs}	Transconductance	$V_{DS} = -2 V, I_D = -1 A$		7.5		S
DYNAMIC	CHARACTERISTICS		·		·	
C _{ISS}	Input Capacitance			315	410	pF
C _{OSS}	Output Capacitance	$V_{GS} = 0 \text{ V}, V_{DS} = -10 \text{ V},$ f = 1 MHz		132	172	pF
C _{RSS}	Reverse Transfer Capacitance	,		7.7	10	pF
Qg	Gate Charge Total (-4.5 V)			1.9	2.5	nC
Q _{gd}	Gate Charge, Gate-to-Drain	V _{DS} = -10 V,		0.23		nC
Q _{gs}	Gate Charge, Gate-to-Source	$I_{DS} = -1 A$		0.48		nC
Q _{g(th)}	Gate Charge at V _{th}			0.31		nC
Q _{OSS}	Output Charge	$V_{DS} = -10 \text{ V}, V_{GS} = 0 \text{ V}$		2.1		nC
t _{d(on)}	Turn On Delay Time			9		ns
t _r	Rise Time	$V_{DS} = -10 \text{ V}, \text{ V}_{GS} = -4.5 \text{ V},$		5		ns
t _{d(off)}	Turn Off Delay Time	$I_{DS} = -1 \text{ A}, \text{ R}_{G} = 0 \Omega$		29		ns
t _f	Fall Time			11		ns
DIODE CI	HARACTERISTICS					
V_{SD}	Diode Forward Voltage	$I_{DS} = -1 \text{ A}, V_{GS} = 0 \text{ V}$		-0.75	-1	V
Q _{rr}	Reverse Recovery Charge			4.3		nC
t _{rr}	Reverse Recovery Time	$V_{DD} = -10 \text{ V}, \text{ I}_{\text{F}} = -1 \text{ A}, \text{ di/dt} = 200 \text{ A/}\mu\text{s}$		9		ns

5.2 Thermal Information

 $T_A = 25^{\circ}C$ unless otherwise stated

	THERMAL METRIC	MIN	TYP	MAX	UNIT
Р	Junction-to-Ambient Thermal Resistance (1) (2)		165		°C/W
	Junction-to-Ambient Thermal Resistance ^{(2) (3)}		95		°C/VV

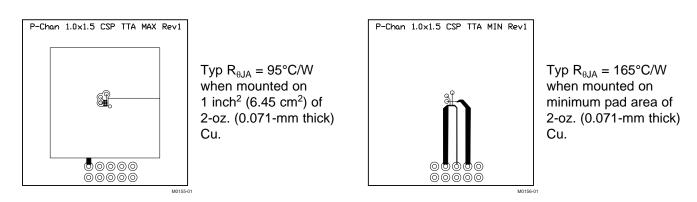
(1) Device mounted on FR4 material with minimum Cu mounting area

Measured with both devices biased in a parallel condition. Device mounted on FR4 material with 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu. (2) (3)

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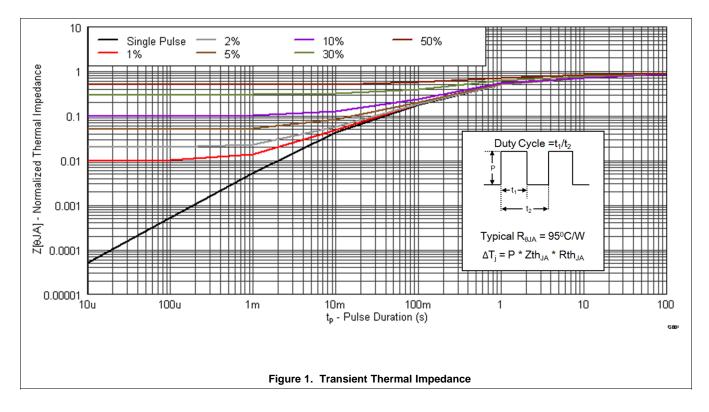


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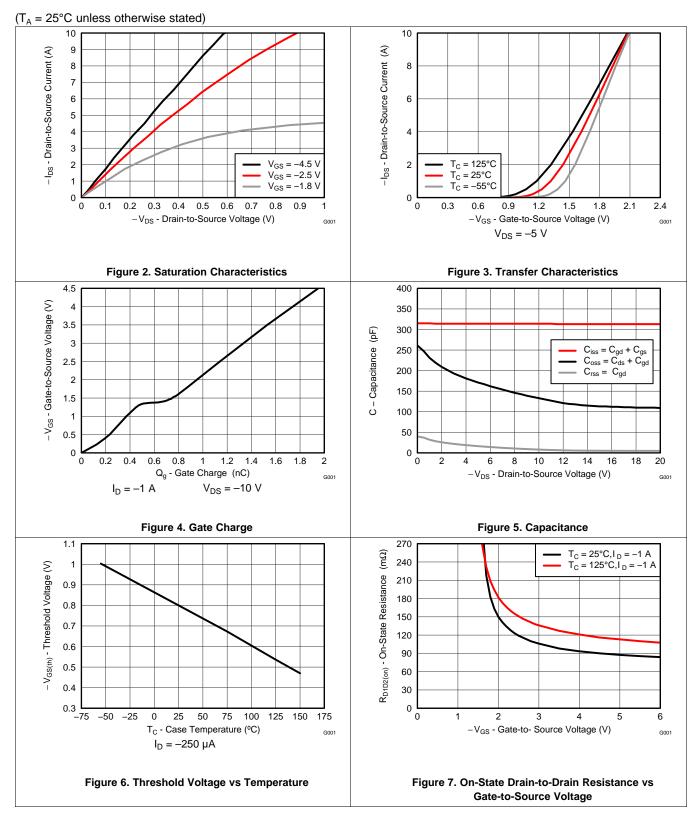
5.3 Typical MOSFET Characteristics

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$



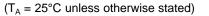


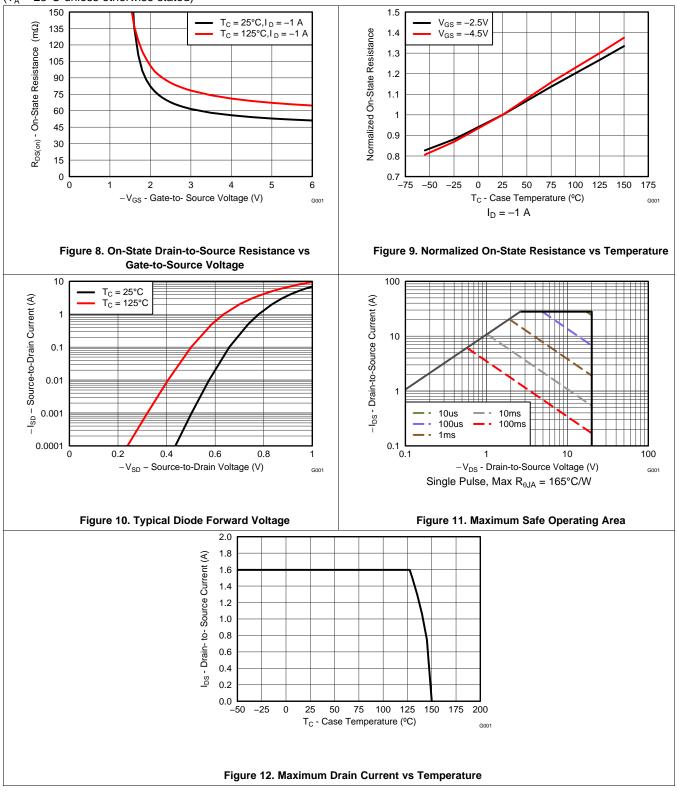
Typical MOSFET Characteristics (continued)





Typical MOSFET Characteristics (continued)







6 Device and Documentation Support

6.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

6.2 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E[™] Online Community *TI's Engineer-to-Engineer (E2E) Community.* Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support TI's Design Support Quickly find helpful E2E forums along with design support tools and contact information for technical support.

6.3 Trademarks

NexFET, E2E are trademarks of Texas Instruments. All other trademarks are the property of their respective owners.

6.4 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

6.5 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

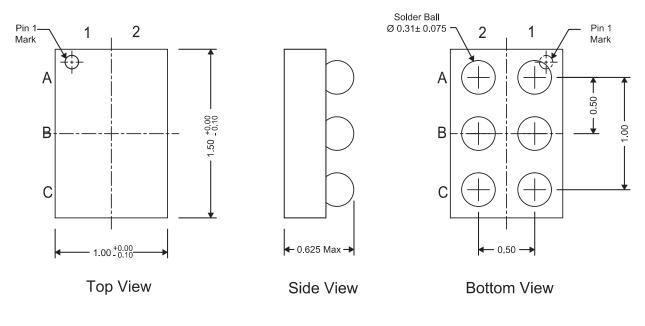
Submit Documentation Feedback

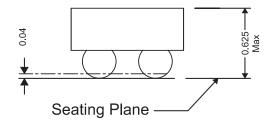
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7 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

7.1 CSD75208W1015 Package Dimensions





Front View

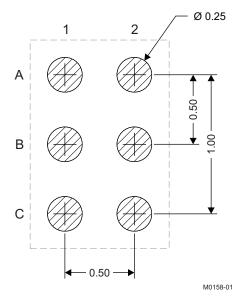
NOTE: All dimensions are in mm (unless otherwise specified).

DESIGNATION
0
Source
Gate1
Drain1
Gate2
Drain2

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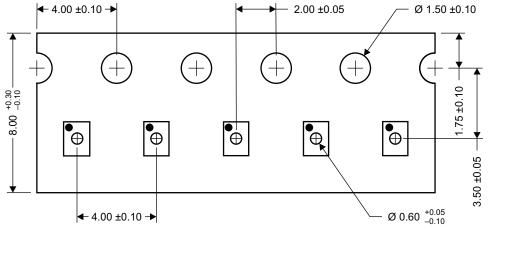


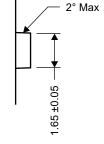
7.2 Recommended PCB Land Pattern

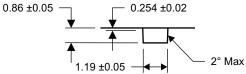


NOTE: All dimensions are in mm (unless otherwise specified).

7.3 Tape and Reel Information







M0159-01

NOTE: All dimensions are in mm (unless otherwise specified).



29-Jun-2018

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
CSD75208W1015	ACTIVE	DSBGA	YZC	6	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	75208	Samples
CSD75208W1015T	ACTIVE	DSBGA	YZC	6	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-55 to 150	75208	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

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